

Single high-speed switching diode Rev. 1 — 12 October 2010

Product data sheet

1. **Product profile**

1.1 General description

Single high-speed switching diode, encapsulated in a SOD882D leadless ultra small Surface-Mounted Device (SMD) plastic package with visible and solderable side pads.

1.2 Features and benefits

- High switching speed: $t_{rr} \le 4$ ns
- Low leakage current
- Repetitive peak reverse voltage: $V_{RRM} \le 100 \text{ V}$
- AEC-Q101 qualified

- Low capacitance
- Reverse voltage: V_R ≤ 100 V
- Ultra small and leadless SMD plastic package
- Solderable side pads

1.3 Applications

- High-speed switching
- General-purpose switching

1.4 Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
I _F	forward current		<u>[1]</u> -	-	215	mA
I _R	reverse current	$V_{R} = 80 \text{ V}$	-	-	0.5	μΑ
V_R	reverse voltage		-	-	100	V
t _{rr}	reverse recovery time		[2] _	-	4	ns

^[1] Device mounted on an FR4 Printed-Circuit Board (PCB) with 60 μ m copper strip line.



^[2] When switched from I_F = 10 mA to I_R = 10 mA; R_L = 100 Ω ; measured at I_R = 1 mA.



Single high-speed switching diode

2. Pinning information

Table 2. Pinning

Pin	Description	Sin	nplified outline	Graphic symbol
1	cathode	<u>[1]</u>		
2	anode		1 2	1 2 006aab040
			Transparent top view	

^[1] The marking bar indicates the cathode.

3. Ordering information

Table 3. Ordering information

Type number	Package				
	Name	Description	Version		
BAS16LD	-	leadless ultra small plastic package; 2 terminals; body $1.0 \times 0.6 \times 0.4$ mm	SOD882D		

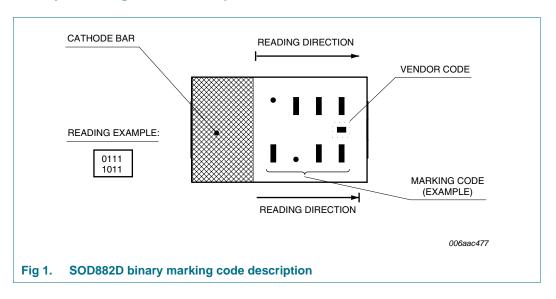
4. Marking

Table 4. Marking codes

Type number	Marking code ^[1]
BAS16LD	1000
	0000

^[1] For SOD882D binary marking code description, see Figure 1.

4.1 Binary marking code description



Single high-speed switching diode

5. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Parameter	Conditions	Min	Max	Unit
repetitive peak reverse voltage		-	100	V
reverse voltage		-	100	V
forward current		<u>[1]</u>	215	mA
repetitive peak forward current	$t_p \leq 0.5~\mu\text{s}; \\ \delta \leq 0.25$	-	500	mA
non-repetitive peak forward current	square wave	<u>[2]</u>		
	t _p = 1 μs	-	4	А
	$t_p = 1 \text{ ms}$	-	1	А
	t _p = 1 s	-	0.5	Α
total power dissipation	$T_{amb} \le 25 ^{\circ}C$	[1][3]	250	mW
junction temperature		-	150	°C
ambient temperature		-55	+150	°C
storage temperature		-65	+150	°C
	repetitive peak reverse voltage reverse voltage forward current repetitive peak forward current non-repetitive peak forward current total power dissipation junction temperature ambient temperature	repetitive peak reverse voltage reverse voltage forward current $ \begin{array}{lll} & t_p \leq 0.5 \; \mu s; \\ \delta \leq 0.25 & \delta \leq 0.25 \\ & \text{non-repetitive peak forward current} & t_p = 1 \; \mu s \\ & t_p = 1 \; ms \\ & t_p = 1 \; s \\ & \text{total power dissipation} & T_{amb} \leq 25 \; ^{\circ}\text{C} \\ & \text{junction temperature} \\ & \text{ambient temperature} \\ \end{array} $	repetitive peak reverse voltage $ \begin{array}{ccccccccccccccccccccccccccccccccccc$	$\begin{tabular}{lllllllllllllllllllllllllllllllllll$

^[1] Device mounted on an FR4 PCB with 60 μm copper strip line.

6. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	[1][2] _	-	500	K/W

^[1] Device mounted on an FR4 PCB with 60 μm copper strip line.

^[2] $T_i = 25$ °C prior to surge.

^[3] Reflow soldering is the only recommended soldering method.

^[2] Reflow soldering is the only recommended soldering method.

Single high-speed switching diode

7. Characteristics

Table 7. Characteristics

 $T_{amb} = 25$ °C unless otherwise specified.

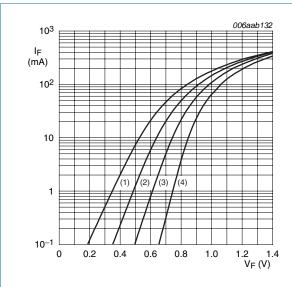
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V_{F}	forward voltage		<u>[1]</u>			
		I _F = 1 mA	-	-	715	mV
		I _F = 10 mA	-	-	855	mV
		I _F = 50 mA	-	-	1	V
		I _F = 150 mA	-	-	1.25	V
I _R reverse current	reverse current	V _R = 25 V	-	-	30	nA
	V _R = 80 V	-	-	0.5	μΑ	
	V _R = 25 V; T _j = 150 °C	-	-	30	μΑ	
		V _R = 80 V; T _j = 150 °C	-	-	50	μΑ
C _d	diode capacitance	$f = 1 MHz; V_R = 0 V$	-	-	1.5	pF
t _{rr}	reverse recovery time		[2] _	-	4	ns
V_{FR}	forward recovery voltage		<u>[3]</u> _	-	1.75	V

^[1] Pulse test: $t_D \le 300 \ \mu s; \ \delta \le 0.02$.

^[2] When switched from I_F = 10 mA to I_R = 10 mA; R_L = 100 Ω ; measured at I_R = 1 mA.

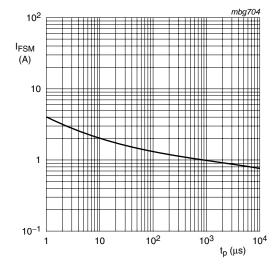
^[3] When switched from $I_F = 10$ mA; $t_r = 20$ ns.

Single high-speed switching diode



- (1) $T_{amb} = 150 \, ^{\circ}C$
- (2) $T_{amb} = 85 \, ^{\circ}C$
- (3) $T_{amb} = 25 \, ^{\circ}C$
- (4) $T_{amb} = -40 \, ^{\circ}C$

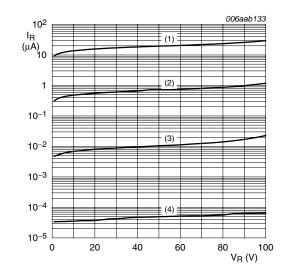
Fig 2. Forward current as a function of forward voltage; typical values



Based on square wave currents.

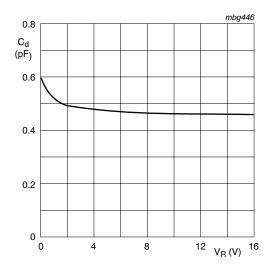
 $T_i = 25$ °C; prior to surge

Fig 3. Non-repetitive peak forward current as a function of pulse duration; maximum values



- (1) $T_{amb} = 150 \, ^{\circ}C$
- (2) $T_{amb} = 85 \, ^{\circ}C$
- (3) $T_{amb} = 25 \, ^{\circ}C$
- (4) $T_{amb} = -40 \, ^{\circ}C$

Fig 4. Reverse current as a function of reverse voltage; typical values

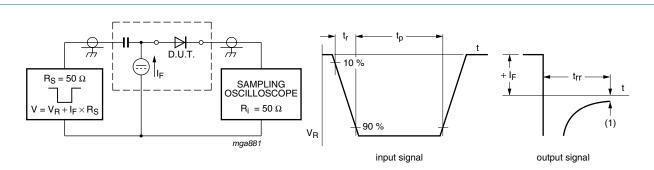


f = 1 MHz; T_{amb} = 25 °C

Fig 5. Diode capacitance as a function of reverse voltage; typical values

Single high-speed switching diode

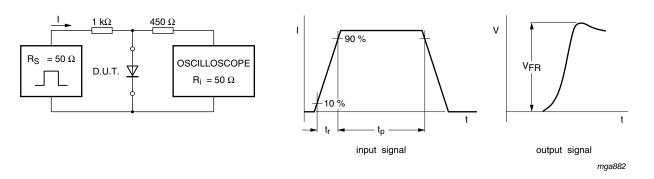
8. Test information



(1) $I_R = 1 \text{ mA}$

Input signal: reverse pulse rise time t_r = 0.6 ns; reverse voltage pulse duration t_p = 100 ns; duty cycle δ = 0.05 Oscilloscope: rise time t_r = 0.35 ns

Fig 6. Reverse recovery time test circuit and waveforms

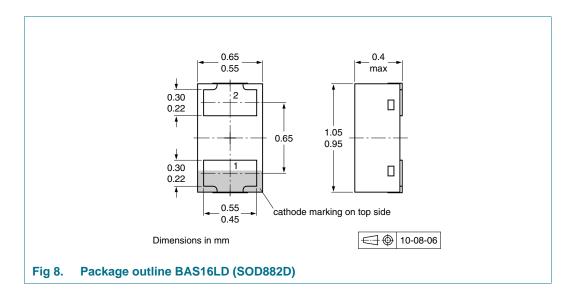


Input signal: forward pulse rise time t_r = 20 ns; forward current pulse duration $t_p \ge 100$ ns; duty cycle $\delta \le 0.005$

Fig 7. Forward recovery voltage test circuit and waveforms

Single high-speed switching diode

9. Package outline



10. Packing information

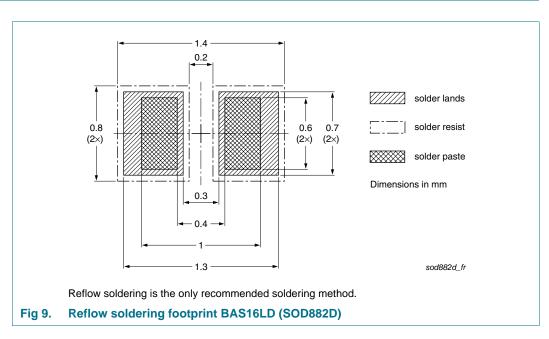
Table 8. Packing methods

The indicated -xxx are the last three digits of the 12NC ordering code.[1]

Type number	Package	Description	Packing quantity
			10000
BAS16LD	SOD882D	2 mm pitch, 8 mm tape and reel	-315

^[1] For further information and the availability of packing methods, see Section 14.

11. Soldering



BAS16LD

BAS16LD NXP Semiconductors

Single high-speed switching diode

12. Revision history

Table 9. **Revision history**

Document ID	Release date	Data sheet status	Change notice	Supersedes
BAS16LD v.1	20101012	Product data sheet	-	-

Single high-speed switching diode

13. Legal information

13.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
- [3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.nxp.com.

13.2 Definitions

Draft — The document is a draft version only. The content is still under internal review and subject to formal approval, which may result in modifications or additions. NXP Semiconductors does not give any representations or warranties as to the accuracy or completeness of information included herein and shall have no liability for the consequences of use of such information.

Short data sheet — A short data sheet is an extract from a full data sheet with the same product type number(s) and title. A short data sheet is intended for quick reference only and should not be relied upon to contain detailed and full information. For detailed and full information see the relevant full data sheet, which is available on request via the local NXP Semiconductors sales office. In case of any inconsistency or conflict with the short data sheet, the full data sheet shall prevail.

Product specification — The information and data provided in a Product data sheet shall define the specification of the product as agreed between NXP Semiconductors and its customer, unless NXP Semiconductors and customer have explicitly agreed otherwise in writing. In no event however, shall an agreement be valid in which the NXP Semiconductors product is deemed to offer functions and qualities beyond those described in the Product data sheet.

13.3 Disclaimers

Limited warranty and liability — Information in this document is believed to be accurate and reliable. However, NXP Semiconductors does not give any representations or warranties, expressed or implied, as to the accuracy or completeness of such information and shall have no liability for the consequences of use of such information.

In no event shall NXP Semiconductors be liable for any indirect, incidental, punitive, special or consequential damages (including - without limitation - lost profits, lost savings, business interruption, costs related to the removal or replacement of any products or rework charges) whether or not such damages are based on tort (including negligence), warranty, breach of contract or any other legal theory.

Notwithstanding any damages that customer might incur for any reason whatsoever, NXP Semiconductors' aggregate and cumulative liability towards customer for the products described herein shall be limited in accordance with the *Terms and conditions of commercial sale* of NXP Semiconductors.

Right to make changes — NXP Semiconductors reserves the right to make changes to information published in this document, including without limitation specifications and product descriptions, at any time and without notice. This document supersedes and replaces all information supplied prior to the publication hereof.

Suitability for use — NXP Semiconductors products are not designed, authorized or warranted to be suitable for use in life support, life-critical or safety-critical systems or equipment, nor in applications where failure or

malfunction of an NXP Semiconductors product can reasonably be expected to result in personal injury, death or severe property or environmental damage. NXP Semiconductors accepts no liability for inclusion and/or use of NXP Semiconductors products in such equipment or applications and therefore such inclusion and/or use is at the customer's own risk.

Applications — Applications that are described herein for any of these products are for illustrative purposes only. NXP Semiconductors makes no representation or warranty that such applications will be suitable for the specified use without further testing or modification.

Customers are responsible for the design and operation of their applications and products using NXP Semiconductors products, and NXP Semiconductors accepts no liability for any assistance with applications or customer product design. It is customer's sole responsibility to determine whether the NXP Semiconductors product is suitable and fit for the customer's applications and products planned, as well as for the planned application and use of customer's third party customer(s). Customers should provide appropriate design and operating safeguards to minimize the risks associated with their applications and products.

NXP Semiconductors does not accept any liability related to any default, damage, costs or problem which is based on any weakness or default in the customer's applications or products, or the application or use by customer's third party customer(s). Customer is responsible for doing all necessary testing for the customer's applications and products using NXP Semiconductors products in order to avoid a default of the applications and the products or of the application or use by customer's third party customer(s). NXP does not accept any liability in this respect.

Limiting values — Stress above one or more limiting values (as defined in the Absolute Maximum Ratings System of IEC 60134) will cause permanent damage to the device. Limiting values are stress ratings only and (proper) operation of the device at these or any other conditions above those given in the Recommended operating conditions section (if present) or the Characteristics sections of this document is not warranted. Constant or repeated exposure to limiting values will permanently and irreversibly affect the quality and reliability of the device.

Terms and conditions of commercial sale — NXP Semiconductors products are sold subject to the general terms and conditions of commercial sale, as published at http://www.nxp.com/profile/terms, unless otherwise agreed in a valid written individual agreement. In case an individual agreement is concluded only the terms and conditions of the respective agreement shall apply. NXP Semiconductors hereby expressly objects to applying the customer's general terms and conditions with regard to the purchase of NXP Semiconductors products by customer.

No offer to sell or license — Nothing in this document may be interpreted or construed as an offer to sell products that is open for acceptance or the grant, conveyance or implication of any license under any copyrights, patents or other industrial or intellectual property rights.

Export control — This document as well as the item(s) described herein may be subject to export control regulations. Export might require a prior authorization from national authorities.

BAS16LD

All information provided in this document is subject to legal disclaimers.

© NXP B.V. 2010. All rights reserved.

Single high-speed switching diode

Quick reference data — The Quick reference data is an extract of the product data given in the Limiting values and Characteristics sections of this document, and as such is not complete, exhaustive or legally binding.

13.4 Trademarks

Notice: All referenced brands, product names, service names and trademarks are the property of their respective owners.

14. Contact information

For more information, please visit: http://www.nxp.com

For sales office addresses, please send an email to: salesaddresses@nxp.com

BAS16LD NXP Semiconductors

Single high-speed switching diode

15. Contents

1	Product profile
1.1	General description
1.2	Features and benefits
1.3	Applications
1.4	Quick reference data 1
2	Pinning information 2
3	Ordering information 2
4	Marking 2
4.1	Binary marking code description 2
5	Limiting values 3
6	Thermal characteristics 3
7	Characteristics 4
8	Test information 6
9	Package outline 7
10	Packing information 7
11	Soldering 7
12	Revision history 8
13	Legal information 9
13.1	Data sheet status 9
13.2	Definitions9
13.3	Disclaimers 9
13.4	Trademarks10
14	Contact information 10
15	Contents 11

Please be aware that important notices concerning this document and the product(s) described herein, have been included in section 'Legal information'.